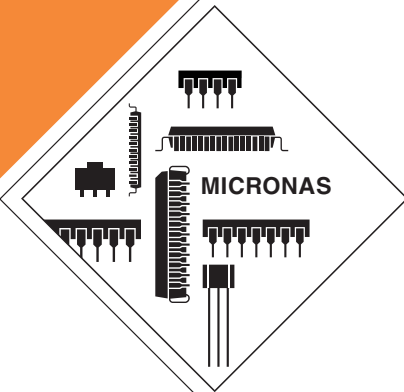


DATA SHEET

# HAL526, HAL535 Hall Effect Sensor Family



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 MICRONAS

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## Hall Effect Sensor Family

**Release Note: Revision bars indicate significant changes to the previous edition.**

### 1. Introduction

The HAL526 and HAL535 are Hall switches produced in CMOS technology. The sensors include a temperature-compensated Hall plate with active offset compensation, a comparator, and an open-drain output transistor. The comparator compares the actual magnetic flux through the Hall plate (Hall voltage) with the fixed reference values (switching points). Accordingly, the output transistor is switched on or off.

The active offset compensation leads to magnetic parameters which are robust against mechanical stress effects. In addition, the magnetic characteristics are constant in the full supply voltage and temperature range.

The sensors are designed for industrial and automotive applications and operate with supply voltages from 3.8 V to 24 V in the ambient temperature range from -40 °C up to 125 °C.

The HAL526 and HAL535 are available in the SMD-package SOT89B-1 and in the leaded versions TO92UA-1 and TO92UA-2.

### 1.1. Features

- operates from 3.8 V to 24 V supply voltage
- operates with static magnetic fields and dynamic magnetic fields up to 10 kHz
- overvoltage protection at all pins
- reverse-voltage protection at  $V_{DD}$ -pin
- magnetic characteristics are robust against mechanical stress effects
- short-circuit protected open-drain output by thermal shut down
- constant switching points over a wide supply voltage range
- the decrease of magnetic flux density caused by rising temperature in the sensor system is compensated by a built-in negative temperature coefficient of the magnetic characteristics
- ideal sensor for window lifter, ignition timing, and revolution counting in extreme automotive and industrial environments
- EMC corresponding to DIN 40839

### 1.2. Family Overview

All sensors have a latching behavior with typically the same sensitivity. The difference between HAL526 and HAL535 is the temperature coefficient of the magnetic switching points.

Type	Switching Behavior	Typical Temperature Coefficient	see Page
526	latching	-2000 ppm/K	18
535	latching	-1000 ppm/K	20

### Latching Sensors:

Both sensors have a latching behavior and require a magnetic north and south pole for correct functioning. The output turns low with the magnetic south pole on the branded side of the package and turns high with the magnetic north pole on the branded side. The output does not change if the magnetic field is removed. For changing the output state, the opposite magnetic field polarity must be applied.

### 1.3. Marking Code

All Hall sensors have a marking on the package surface (branded side). This marking includes the name of the sensor and the temperature range.

Type	Temperature Range	
	K	E
HAL526	526K	526E
HAL535	535K	535E

#### 1.3.1. Special Marking of Prototype Parts

Prototype parts are coded with an underscore beneath the temperature range letter on each IC. They may be used for lab experiments and design-ins but are not intended to be used for qualification tests or as production parts.

### 1.4. Operating Junction Temperature Range ( $T_J$ )

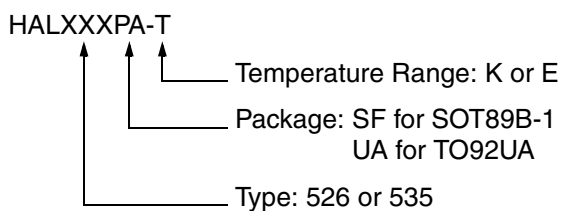
The Hall sensors from Micronas are specified to the chip temperature (junction temperature  $T_J$ ).

**K:**  $T_J = -40\text{ °C to }+140\text{ °C}$

**E:**  $T_J = -40\text{ °C to }+100\text{ °C}$

The relationship between ambient temperature ( $T_A$ ) and junction temperature is explained in Section 5.1. on page 22.

### 1.5. Hall Sensor Package Codes



Example: **HAL526UA-E**

- Type: 526
- Package: TO92UA
- Temperature Range:  $T_J = -40\text{ °C to }+100\text{ °C}$

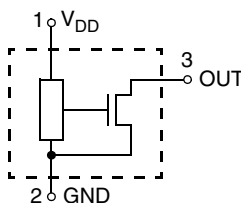
Hall sensors are available in a wide variety of packaging versions and quantities. For more detailed information, please refer to the brochure: "Hall Sensors: Ordering Codes, Packaging, Handling".

### 1.6. Solderability

all packages: according to IEC68-2-58

During soldering reflow processing and manual reworking, a component body temperature of 260 °C should not be exceeded.

### 1.7. Pin Connections



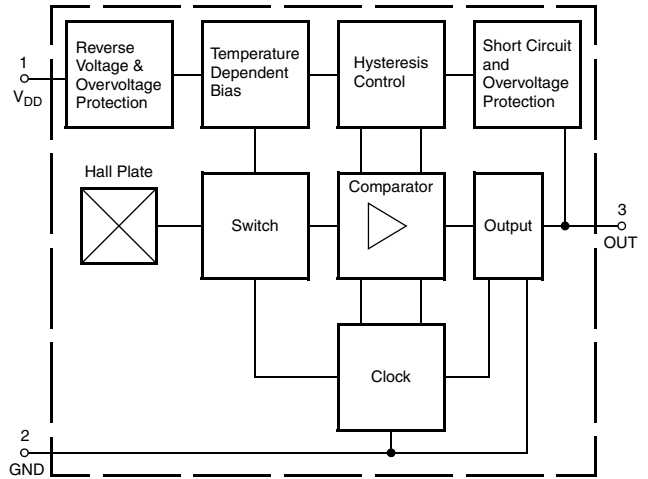
**Fig. 1-1:** Pin configuration

**2. Functional Description**

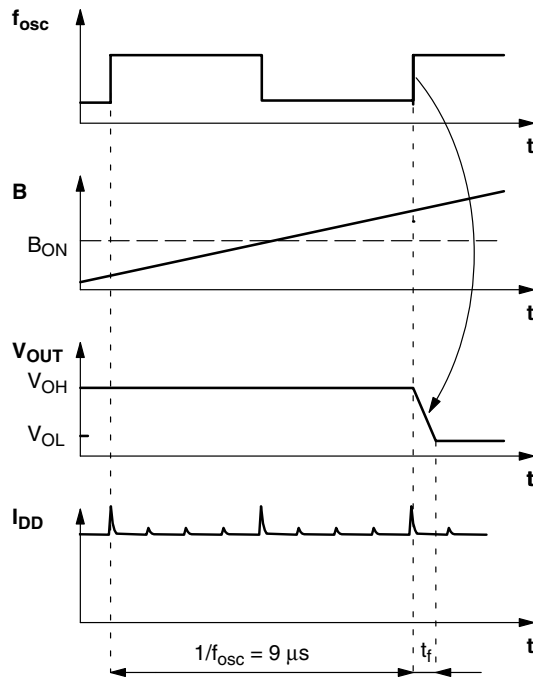
The Hall effect sensor is a monolithic integrated circuit that switches in response to magnetic fields. If a magnetic field with flux lines perpendicular to the sensitive area is applied to the sensor, the biased Hall plate forces a Hall voltage proportional to this field. The Hall voltage is compared with the actual threshold level in the comparator. The temperature-dependent bias increases the supply voltage of the Hall plates and adjusts the switching points to the decreasing induction of magnets at higher temperatures. If the magnetic field exceeds the threshold levels, the open drain output switches to the appropriate state. The built-in hysteresis eliminates oscillation and provides switching behavior of output without bouncing.

Magnetic offset caused by mechanical stress is compensated for by using the “switching offset compensation technique”. Therefore, an internal oscillator provides a two phase clock. The Hall voltage is sampled at the end of the first phase. At the end of the second phase, both sampled and actual Hall voltages are averaged and compared with the actual switching point. Subsequently, the open drain output switches to the appropriate state. The time from crossing the magnetic switching level to switching of output can vary between zero and  $1/f_{osc}$ .

Shunt protection devices clamp voltage peaks at the Output-pin and  $V_{DD}$ -pin together with external series resistors. Reverse current is limited at the  $V_{DD}$ -pin by an internal series resistor up to  $-15$  V. No external reverse protection diode is needed at the  $V_{DD}$ -pin for reverse voltages ranging from  $0$  V to  $-15$  V.



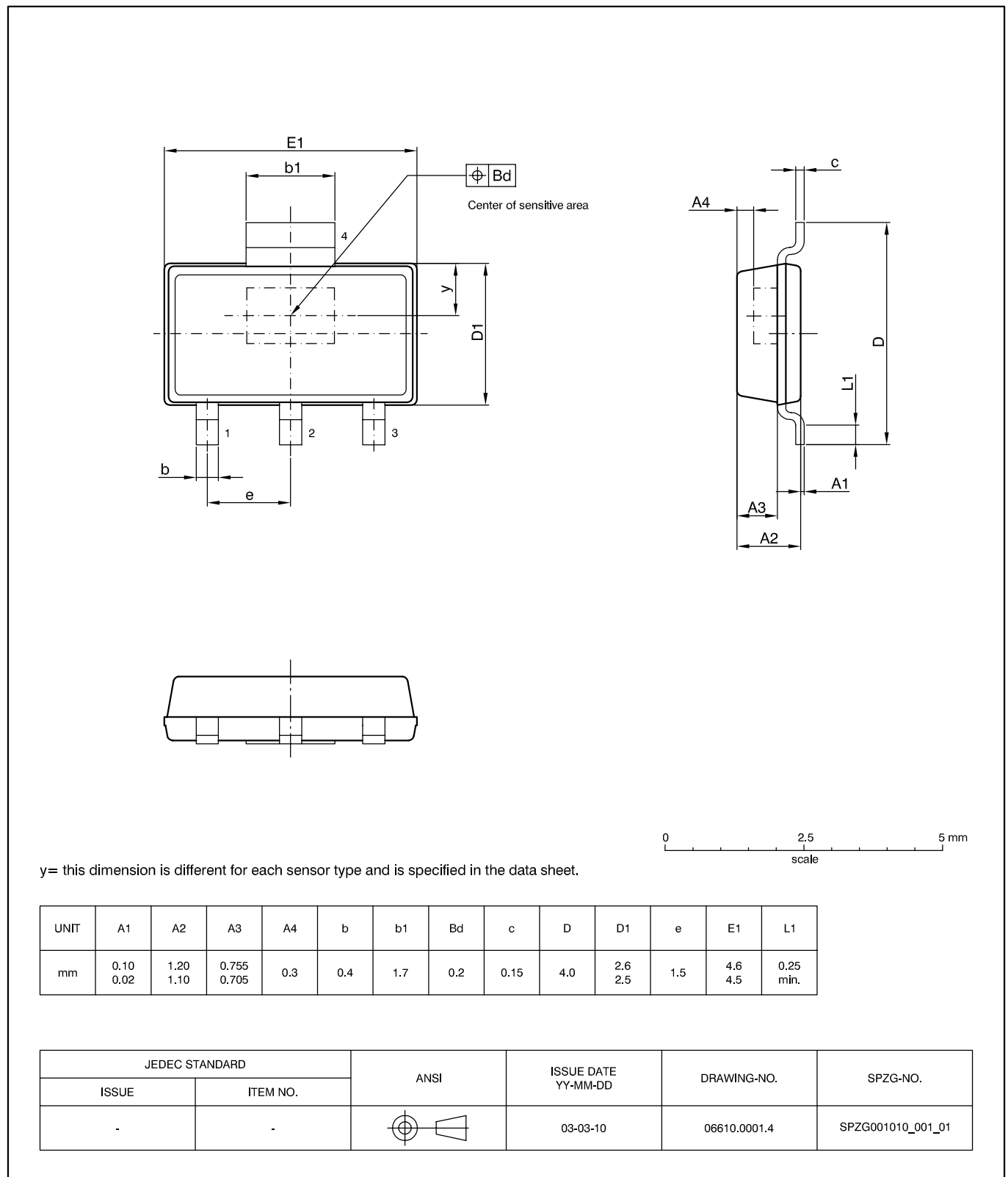
**Fig. 2-1:** HAL526, HAL535 block diagram



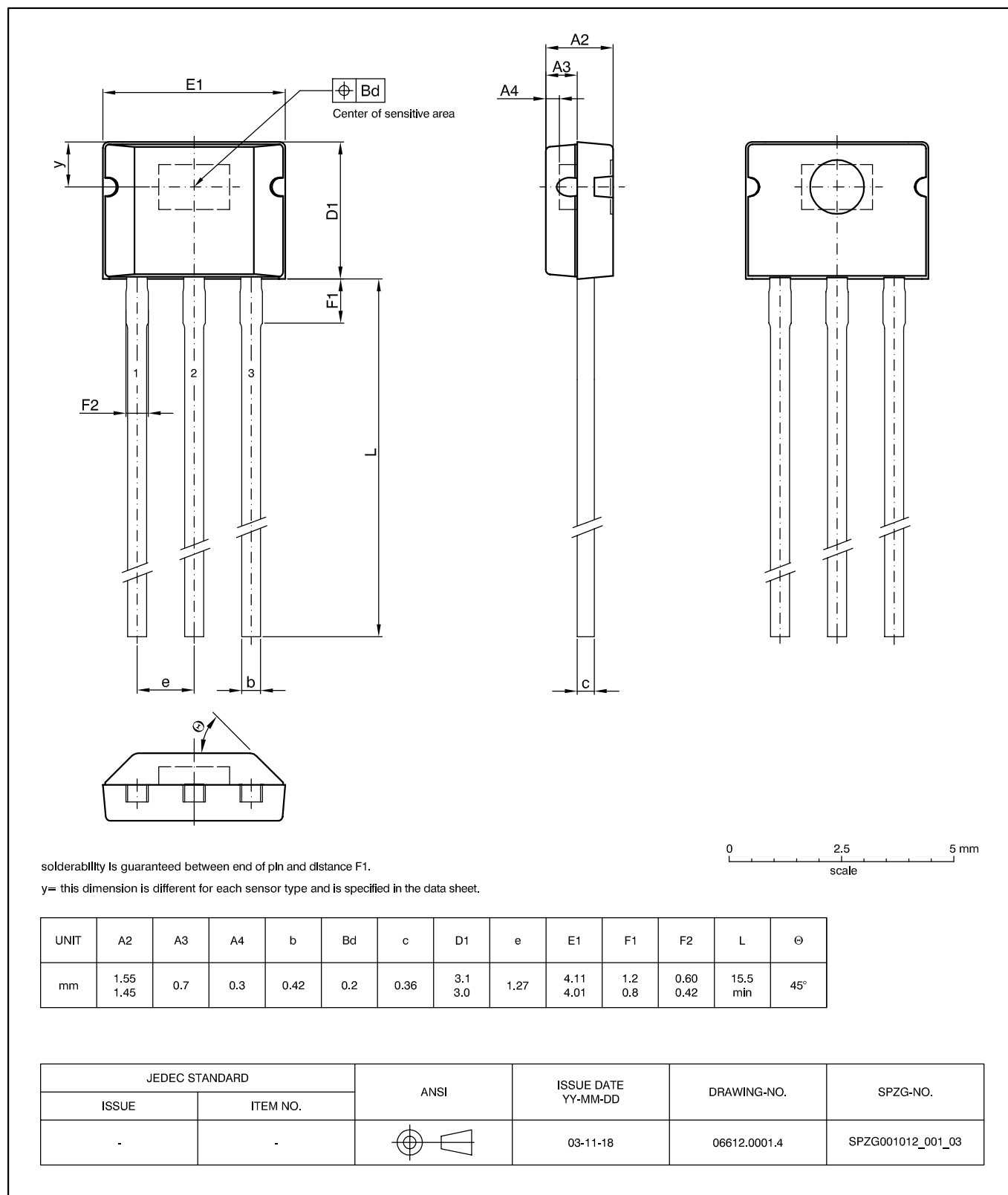
**Fig. 2-2:** Timing diagram

3. Specifications

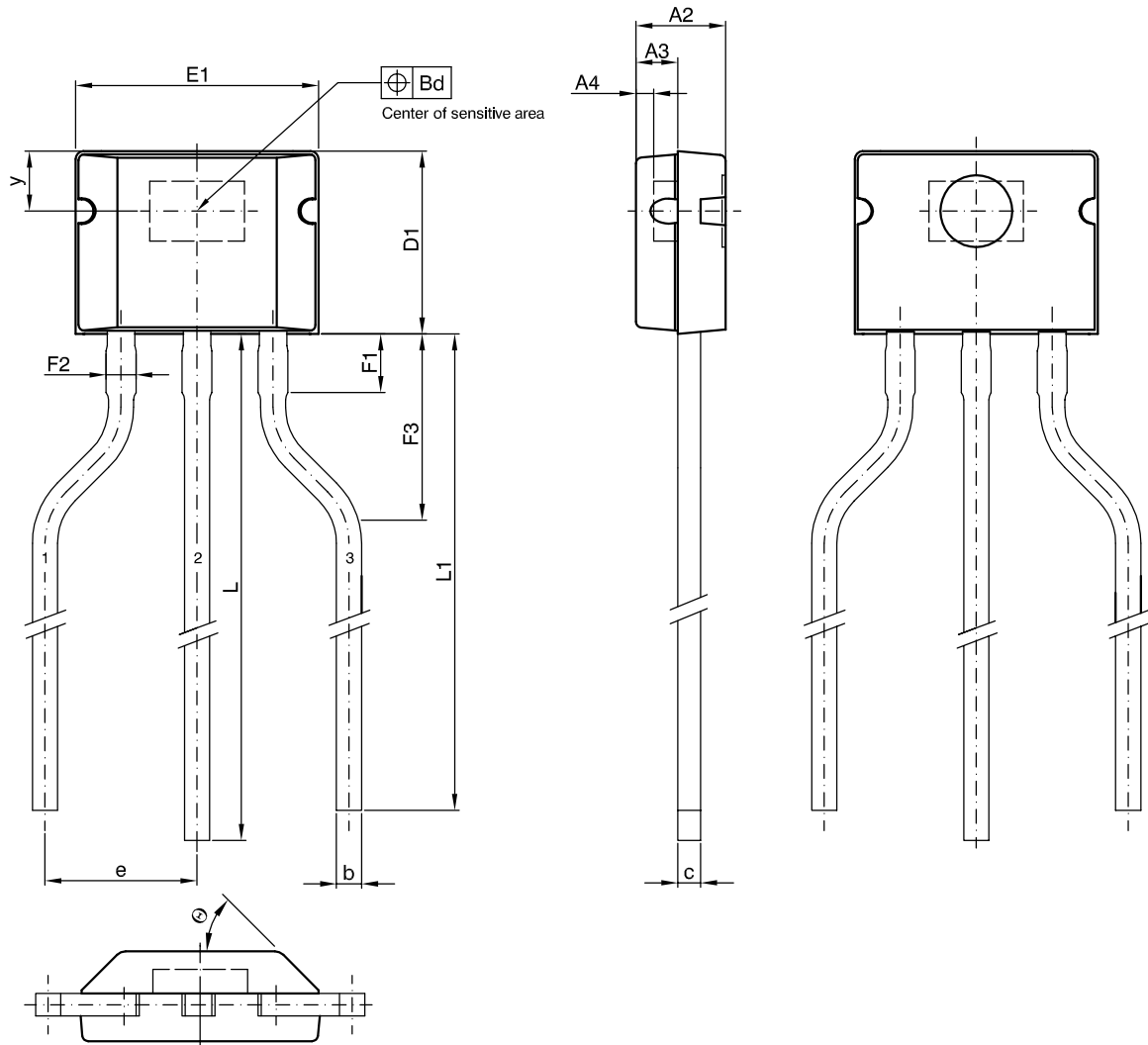
3.1. Outline Dimensions



**Fig. 3-1:**  
**SOT89B-1: Plastic Small Outline Transistor package, 4 leads**  
 Weight approximately 0.039 g

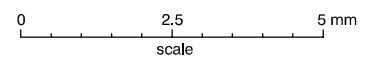


**Fig. 3-2:**  
**TO92UA-2:** Plastic Transistor Standard UA package, 3 leads, not spread  
 Weight approximately 0.105 g



solderability is guaranteed between end of pin and distance F1.

y= this dimension is different for each sensor type and is specified in the data sheet.



UNIT	A2	A3	A4	b	Bd	c	D1	e	E1	F1	F2	F3	L	L1	θ
mm	1.55 1.45	0.7	0.3	0.42	0.2	0.36	3.1 3.0	2.54	4.11 4.01	1.2 0.8	0.60 0.42	4.0 2.0	15.5 min	14.5 min	45°

JEDEC STANDARD		ANSI	ISSUE DATE YY-MM-DD	DRAWING-NO.	SPZG-NO.
ISSUE	ITEM NO.				
-	-		03-11-18	06616.0001.4	SPZG001016_001_02

**Fig. 3-3:**  
**TO92UA-1:** Plastic Transistor Standard UA package, 3 leads, spread  
 Weight approximately 0.105 g



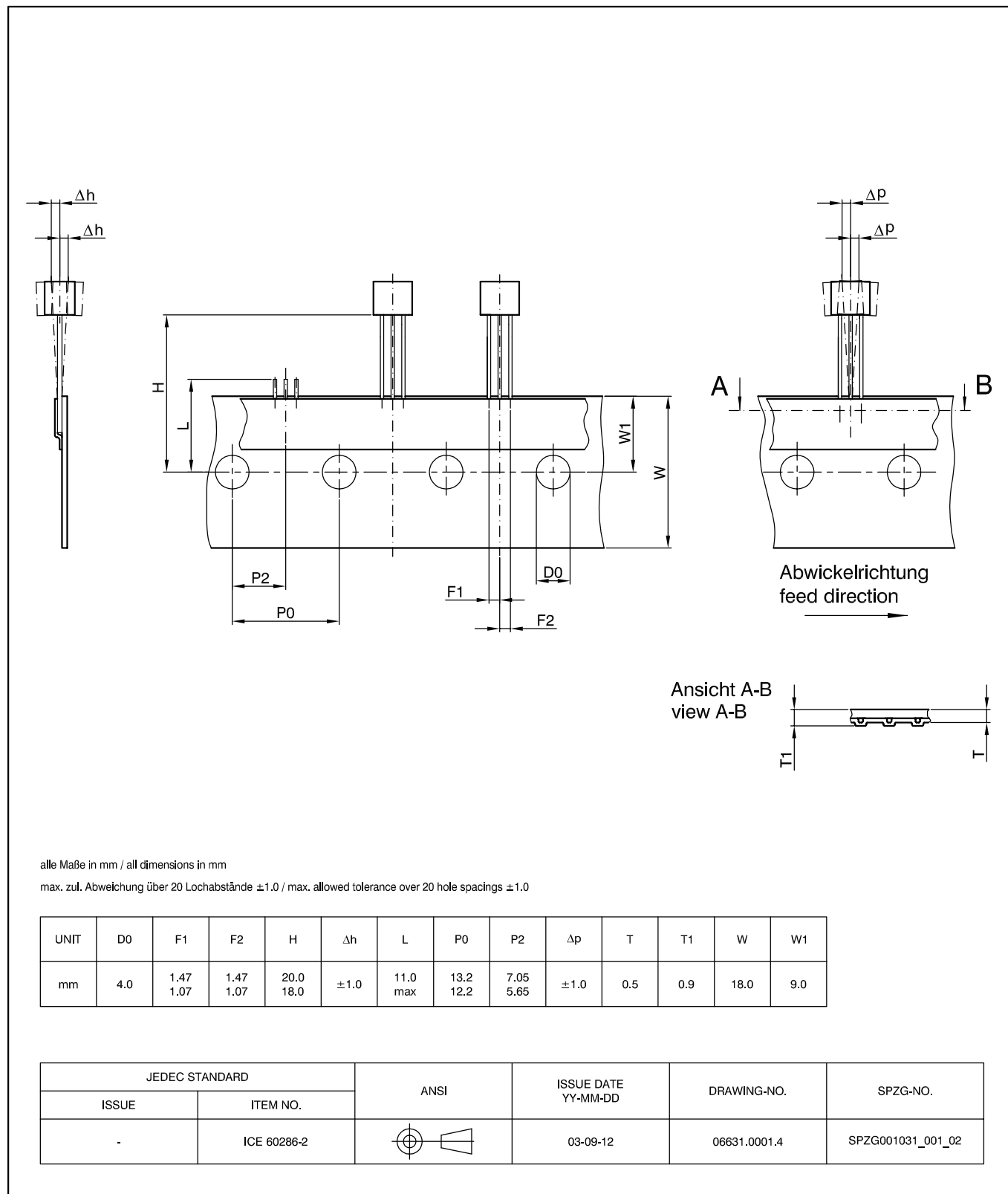
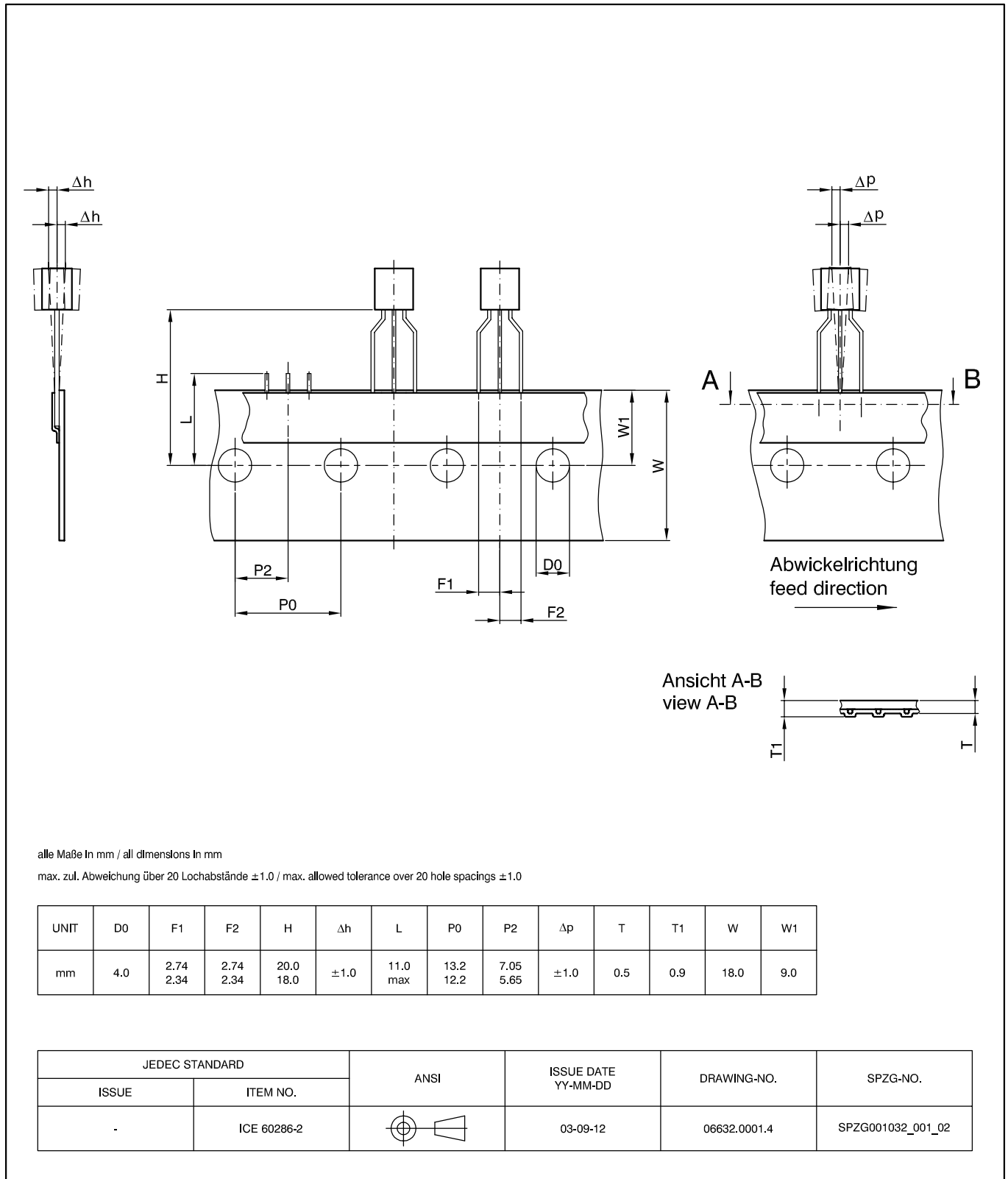


Fig. 3-4:  
 T092UA-2: Dimensions ammpack inline, not spread



**Fig. 3-5:**  
**T092UA-1: Dimensions ammpack inline, spread**

### 3.2. Dimensions of Sensitive Area

0.25 mm × 0.12 mm

### 3.3. Positions of Sensitive Areas

	SOT89B-1	TO92UA-1/-2
x	center of the package	center of the package
y	0.95 mm nominal	1.0 mm nominal

### 3.4. Absolute Maximum Ratings

Stresses beyond those listed in the “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these conditions is not implied. Exposure to absolute maximum rating conditions for extended periods will affect device reliability.

This device contains circuitry to protect the inputs and outputs against damage due to high static voltages or electric fields; however, it is advised that normal precautions be taken to avoid application of any voltage higher than absolute maximum-rated voltages to this high-impedance circuit.

All voltages listed are referenced to ground.

Symbol	Parameter	Pin No.	Limit Values		Unit
			Min.	Max.	
V <sub>DD</sub>	Supply Voltage	1	-15	28 <sup>1)</sup>	V
V <sub>O</sub>	Output Voltage	3	-0.3	28 <sup>1)</sup>	V
I <sub>O</sub>	Continuous Output On Current	3	-	50 <sup>1)</sup>	mA
T <sub>J</sub>	Junction Temperature Range		-40 -40	150 170 <sup>2)</sup>	°C
<sup>1)</sup> as long as T <sub>Jmax</sub> is not exceeded <sup>2)</sup> t < 1000h					

#### 3.4.1. Storage and Shelf Life

The permissible storage time (shelf life) of the sensors is unlimited, provided the sensors are stored at a maximum of 30 °C and a maximum of 85% relative humidity. At these conditions, no Dry Pack is required.

Solderability is guaranteed for one year from the date code on the package. Solderability has been tested after storing the devices for 16 hours at 155 °C. The wettability was more than 95%.

### 3.5. Recommended Operating Conditions

Functional operation of the device beyond those indicated in the “Recommended Operating Conditions” of this specification is not implied, may result in unpredictable behavior of the device and may reduce reliability and lifetime.

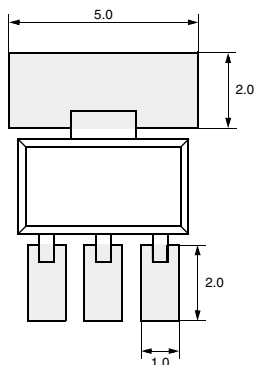
All voltages listed are referenced to ground.

Symbol	Parameter	Pin No.	Limit Values		Unit
			Min.	Max.	
$V_{DD}$	Supply Voltage	1	3.8	24	V
$I_O$	Continuous Output On Current	3	0	20	mA
$V_O$	Output Voltage (output switched off)	3	0	24	V

### 3.6. Characteristics

at  $T_J = -40\text{ }^\circ\text{C}$  to  $+140\text{ }^\circ\text{C}$ ,  $V_{DD} = 3.8\text{ V}$  to  $24\text{ V}$ ,  
 at Recommended Operation Conditions if not otherwise specified in the column "Conditions".  
 Typical Characteristics for  $T_J = 25\text{ }^\circ\text{C}$  and  $V_{DD} = 12\text{ V}$ .

Symbol	Parameter	Pin No.	Limit Values			Unit	Test Conditions
			Min.	Typ.	Max.		
$I_{DD}$	Supply Current	1	2.3	3	4.2	mA	$T_J = 25\text{ }^\circ\text{C}$
$I_{DD}$	Supply Current over Temperature Range	1	1.6	3	5.2	mA	
$V_{DDZ}$	Overshoot Protection at Supply	1	–	28.5	32	V	$I_{DD} = 25\text{ mA}$ , $T_J = 25\text{ }^\circ\text{C}$ , $t = 20\text{ ms}$
$V_{OZ}$	Overshoot Protection at Output	3	–	28	32	V	$I_{OH} = 25\text{ mA}$ , $T_J = 25\text{ }^\circ\text{C}$ , $t = 20\text{ ms}$
$V_{OL}$	Output Voltage	3	–	130	280	mV	$I_{OL} = 20\text{ mA}$ , $T_J = 25\text{ }^\circ\text{C}$
$V_{OL}$	Output Voltage over Temperature Range	3	–	130	400	mV	$I_{OL} = 20\text{ mA}$
$I_{OH}$	Output Leakage Current	3	–	0.06	0.1	$\mu\text{A}$	Output switched off, $T_J = 25\text{ }^\circ\text{C}$ , $V_{OH} = 3.8\text{ to }24\text{ V}$
$I_{OH}$	Output Leakage Current over Temperature Range	3	–	–	10	$\mu\text{A}$	Output switched off, $T_J \leq 150\text{ }^\circ\text{C}$ , $V_{OH} = 3.8\text{ to }24\text{ V}$
$f_{osc}$	Internal Oscillator Chopper Frequency	–	120	150	–	kHz	$T_J = 25\text{ }^\circ\text{C}$
$f_{osc}$	Internal Oscillator Chopper Frequency over Temperature Range	–	100	150	–	kHz	
$t_{en(O)}$	Enable Time of Output after Setting of $V_{DD}$	1	–	30	70	$\mu\text{s}$	$V_{DD} = 12\text{ V}$ $B > B_{ON} + 2\text{ mT}$ or $B < B_{OFF} - 2\text{ mT}$
$t_r$	Output Rise Time	3	–	75	400	ns	$V_{DD} = 12\text{ V}$ , $R_L = 820\text{ Ohm}$ , $C_L = 20\text{ pF}$
$t_f$	Output Fall Time	3	–	50	400	ns	
$R_{thJSB}$ case SOT89B-1	Thermal Resistance Junction to Substrate Backside	–	–	150	200	K/W	Fiberglass Substrate 30 mm x 10 mm x 1.5 mm, pad size (see Fig. 3–6)
$R_{thJA}$ case TO92UA-1, TO92UA-2	Thermal Resistance Junction to Soldering Point	–	–	150	200	K/W	



**Fig. 3–6:** Recommended pad size SOT89B-1  
 Dimensions in mm

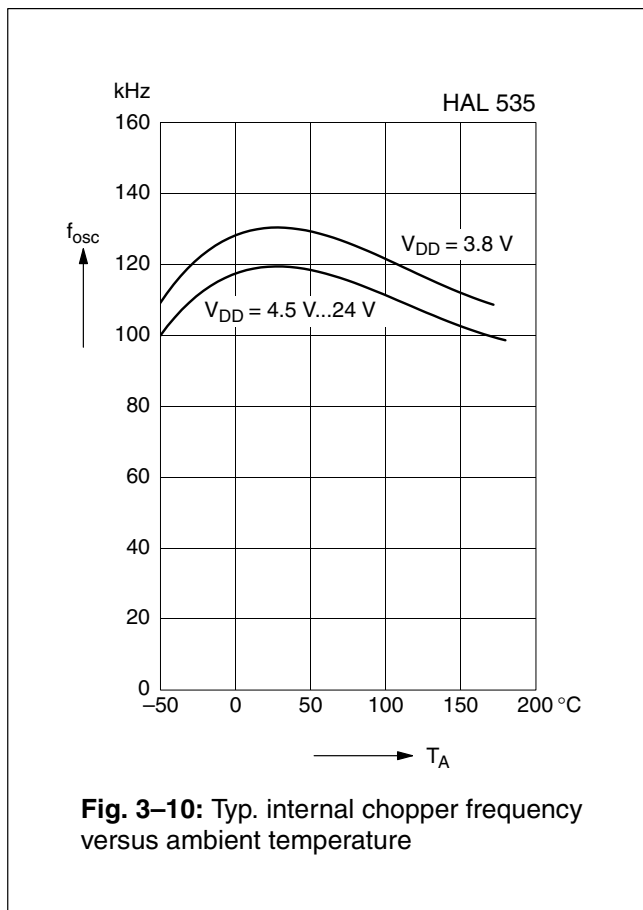
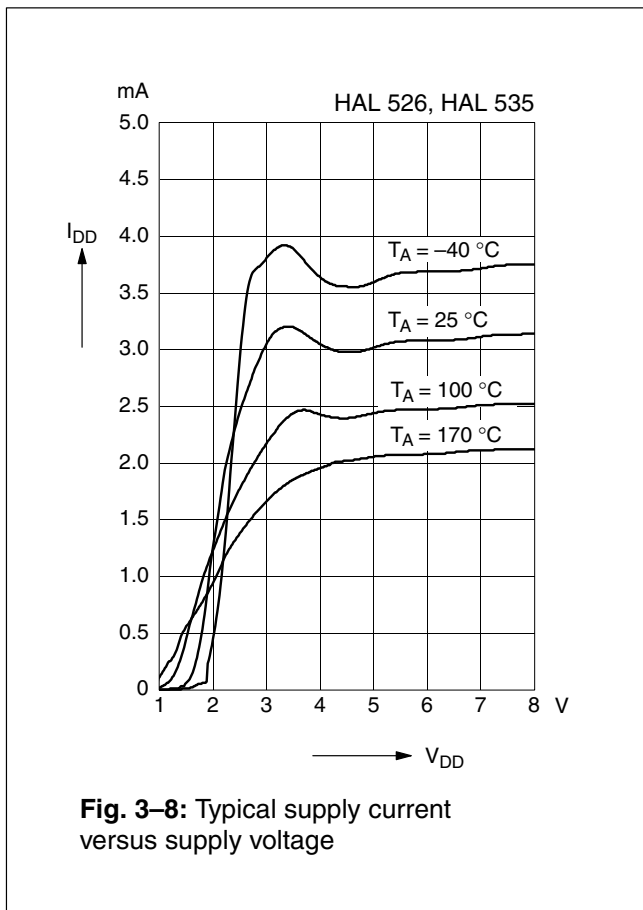
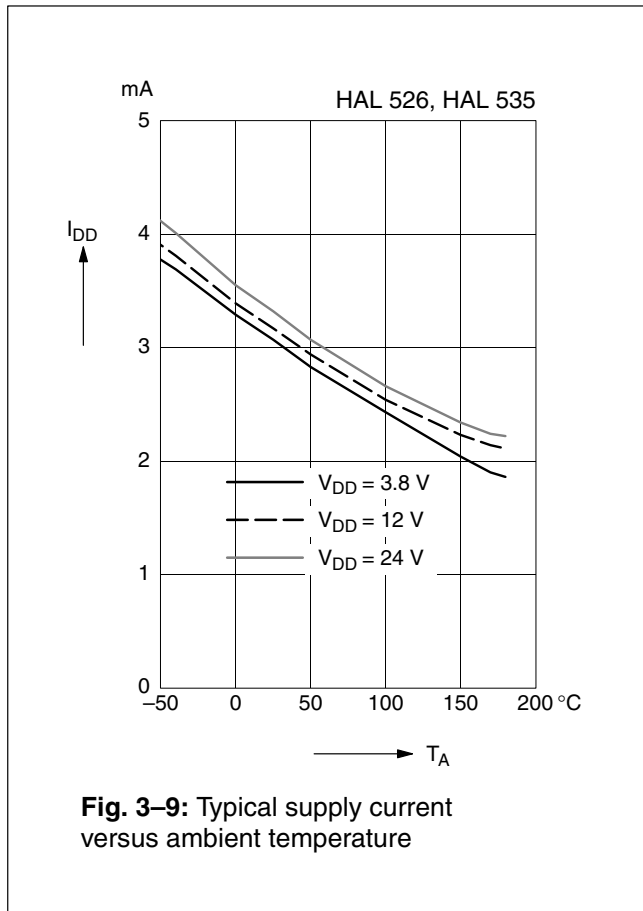
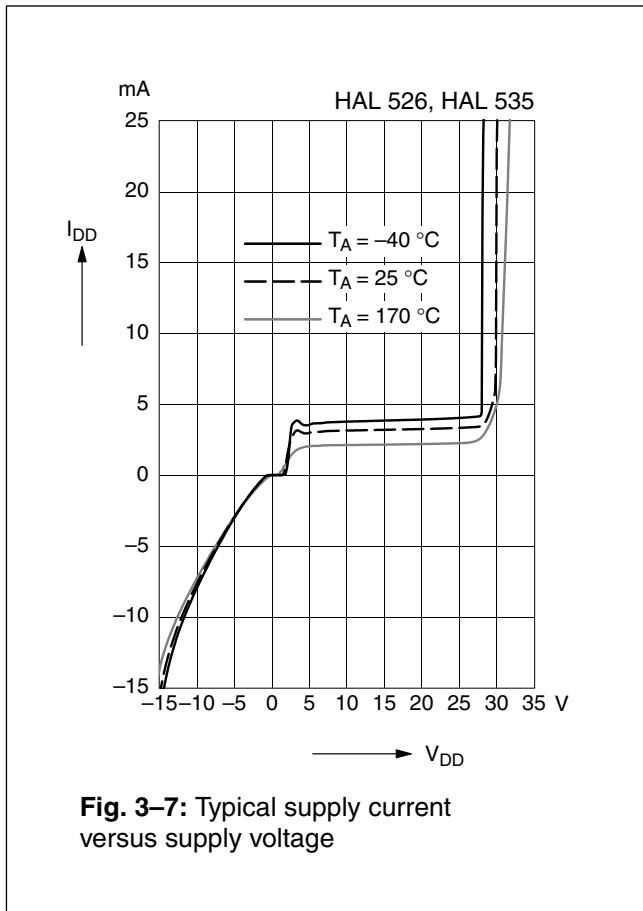
**3.7. Magnetic Characteristics Overview** at  $T_J = -40\text{ °C}$  to  $+140\text{ °C}$ ,  $V_{DD} = 3.8\text{ V}$  to  $24\text{ V}$ ,  
Typical Characteristics for  $V_{DD} = 12\text{ V}$

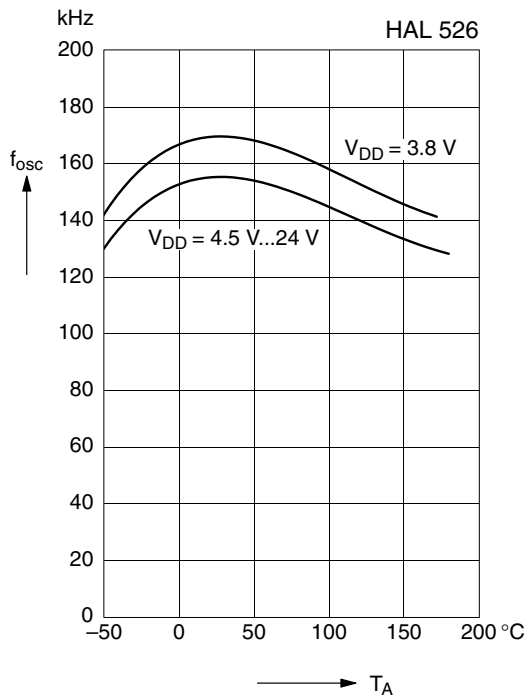
Magnetic flux density values of switching points.

Positive flux density values refer to the magnetic south pole at the branded side of the package.

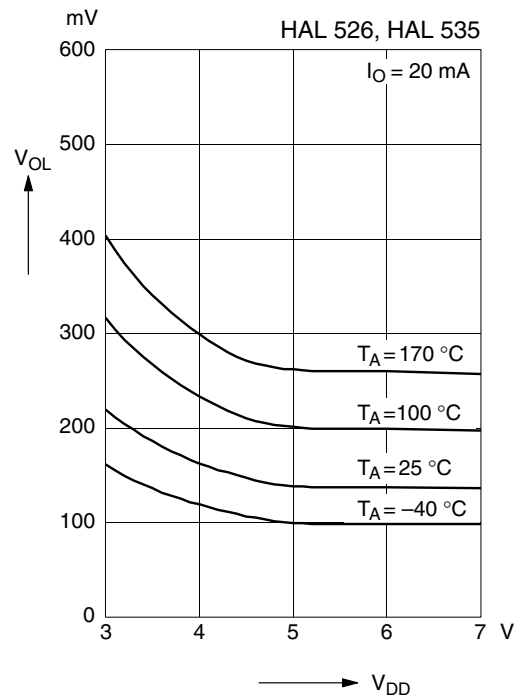
Sensor Switching Type	Parameter $T_J$	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
HAL526 latching	-40 °C	11.8	15.8	19.2	-19.2	-15.8	-11.8	27.4	31.6	35.8	mT
	25 °C	11	14	17	-17	-14	-11	24	28	32	mT
	140 °C	6.5	10	14	-14	-10	-6.5	16	20	26	mT
HAL535 latching	-40 °C	12	15	18	-18	-15	-12	25	30	35	mT
	25 °C	11	13.8	17	-17	-13.8	-11	23	27.6	32	mT
	140 °C	7	12.5	17	-17	-12.5	-7	18	25	31	mT

**Note:** For detailed descriptions of the individual types, see pages 18 and following.

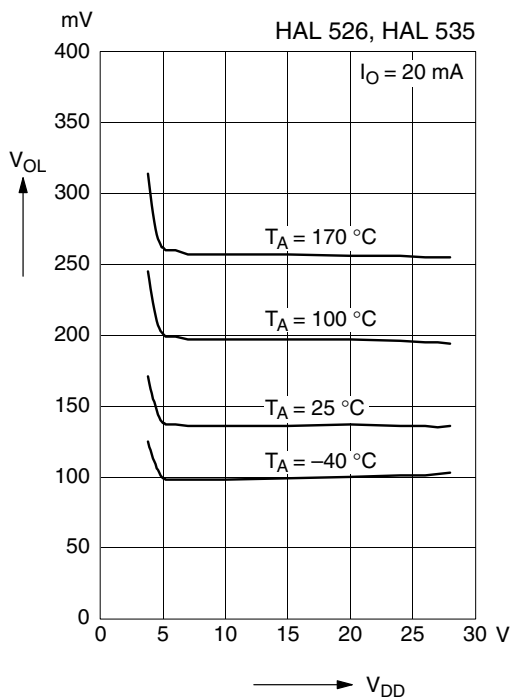




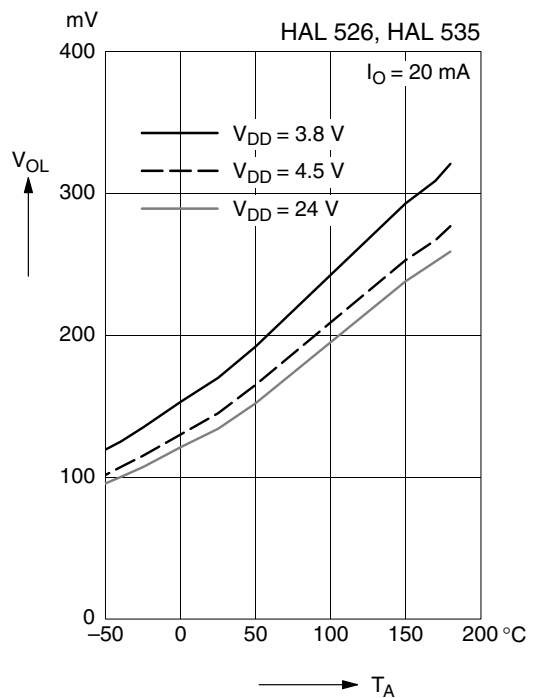
**Fig. 3-11:** Typ. internal chopper frequency versus ambient temperature



**Fig. 3-13:** Typical output low voltage versus supply voltage

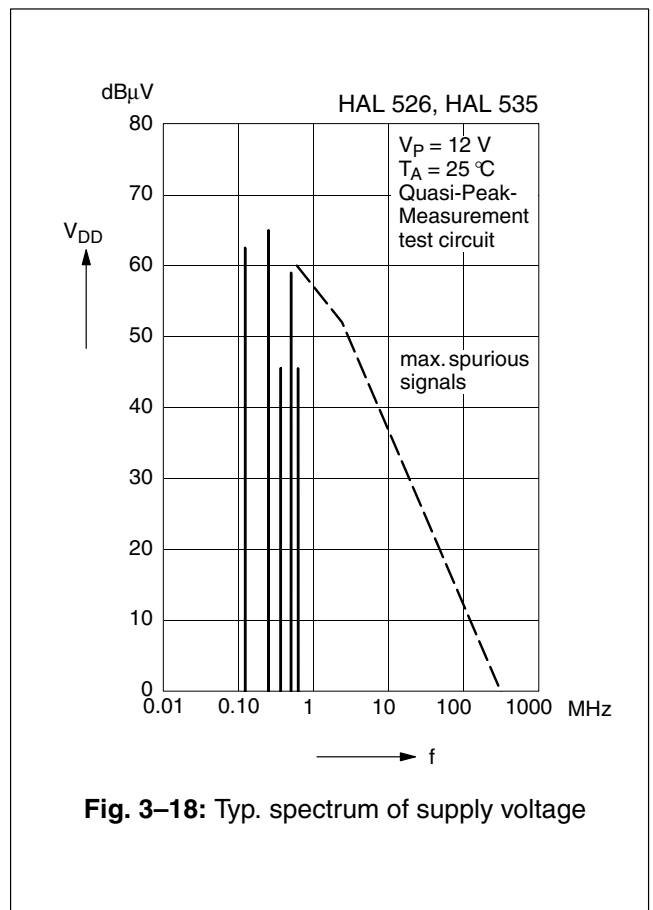
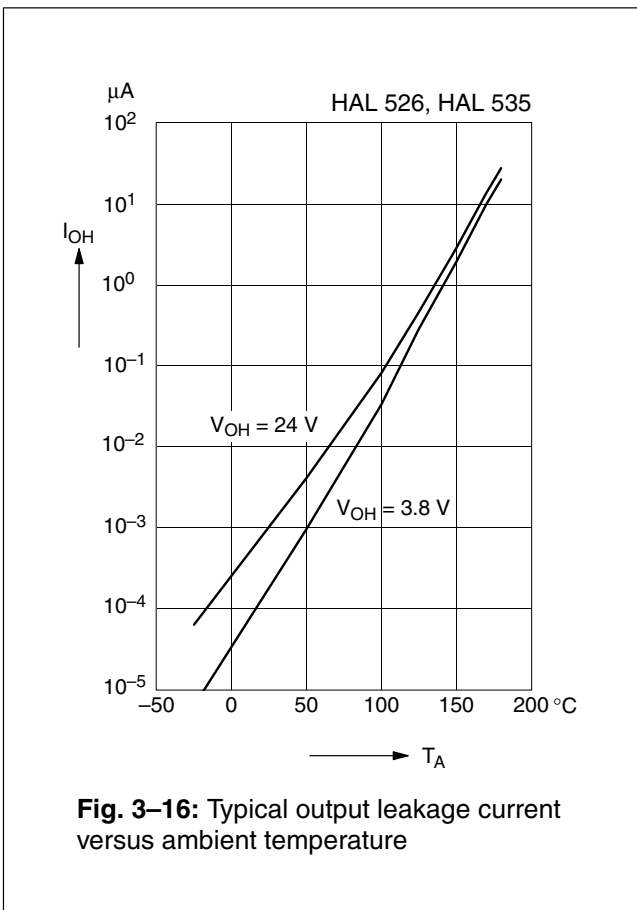
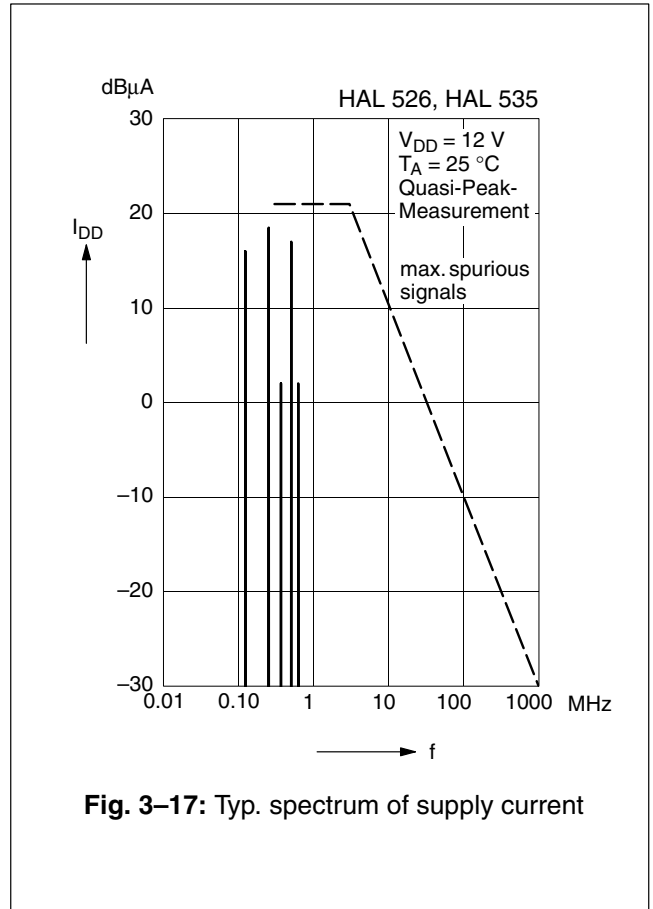
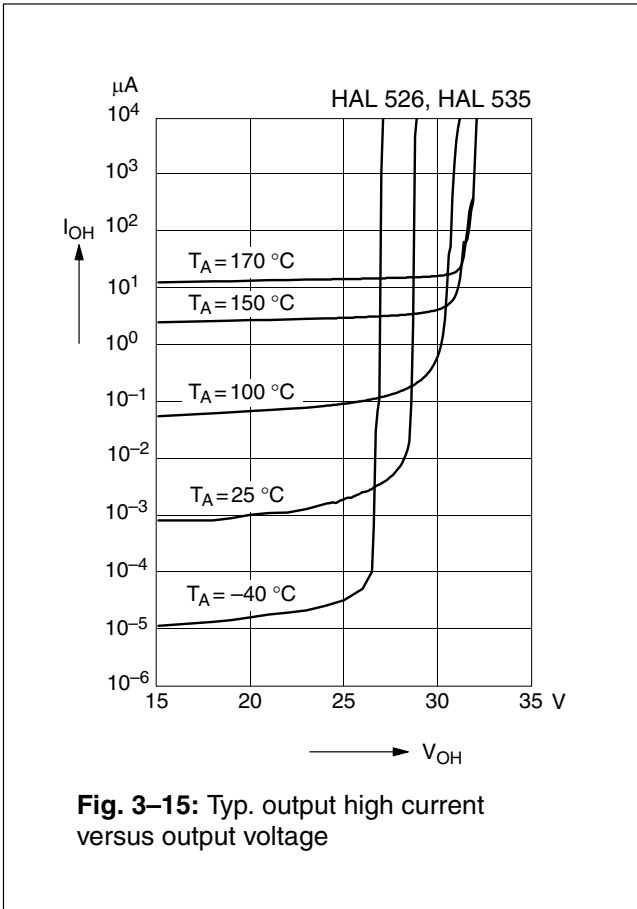


**Fig. 3-12:** Typical output low voltage versus supply voltage



**Fig. 3-14:** Typical output low voltage versus ambient temperature





**4. Type Description**

**4.1. HAL526**

The HAL526 is a latching sensor (see Fig. 4–1).

The output turns low with the magnetic south pole on the branded side of the package and turns high with the magnetic north pole on the branded side. The output does not change if the magnetic field is removed. For changing the output state, the opposite magnetic field polarity must be applied.

For correct functioning in the application, the sensor requires both magnetic polarities (north and south) on the branded side of the package.

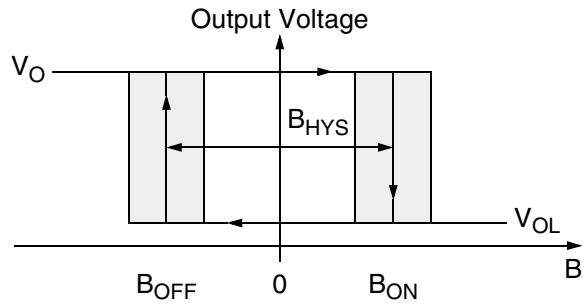
**Magnetic Features:**

- switching type: latching
- low sensitivity
- typical  $B_{ON}$ : 14 mT at room temperature
- typical  $B_{OFF}$ : -14 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 10 kHz
- typical temperature coefficient of magnetic switching points is -2000 ppm/K

**Applications**

The HAL526 is an optimal sensor for applications with alternating magnetic signals such as:

- multipole magnet applications,
- rotating speed measurement,
- commutation of brushless DC motors, and
- window lifter.



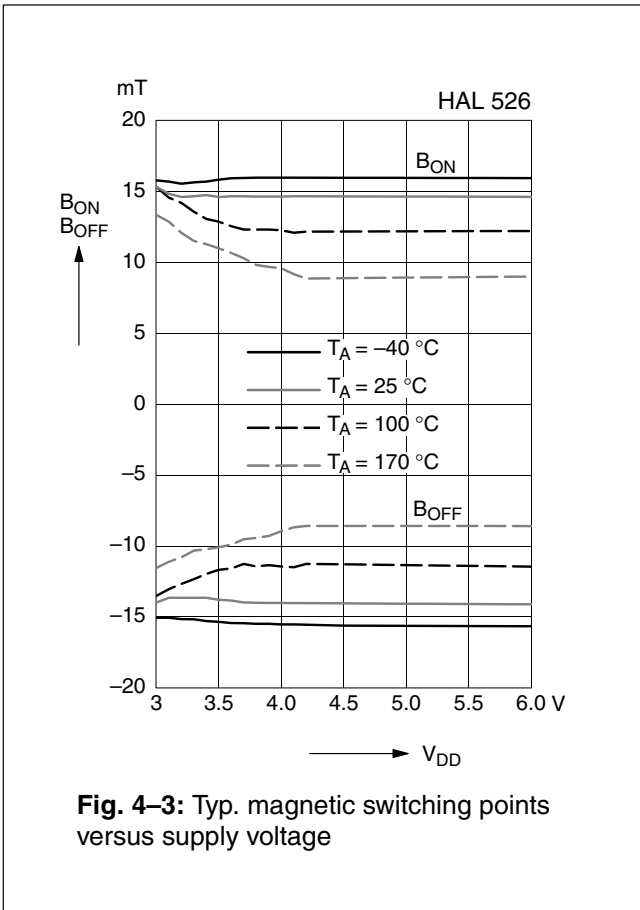
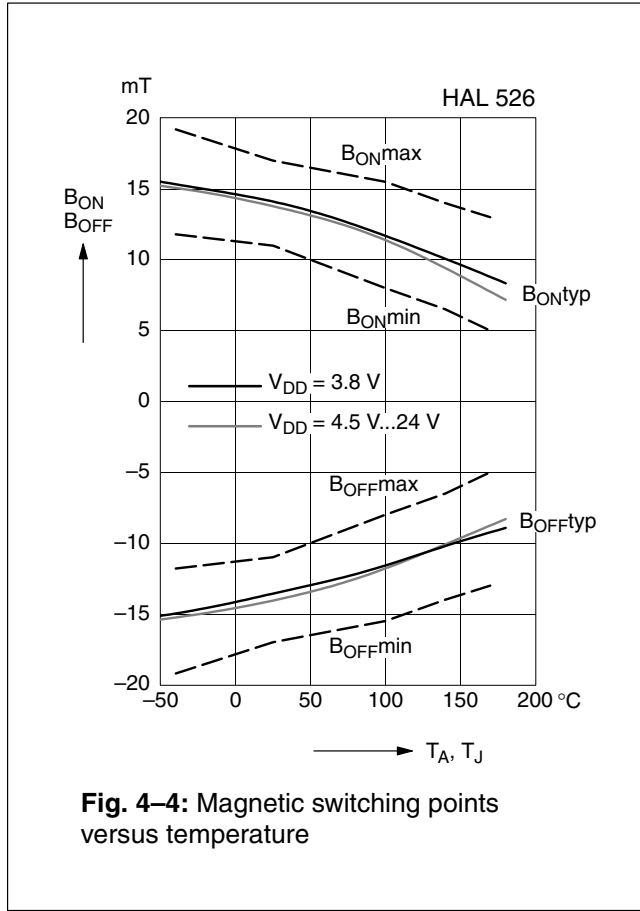
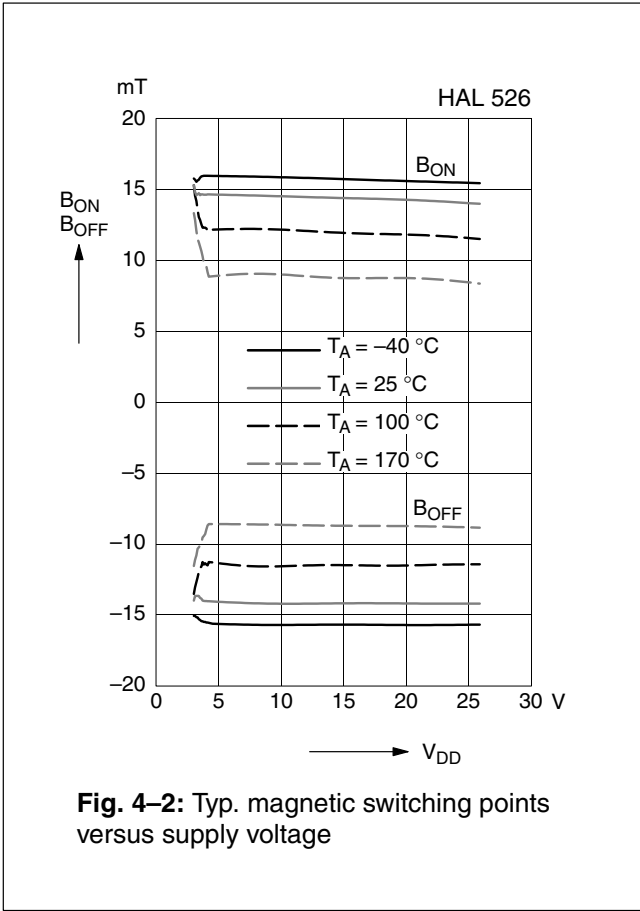
**Fig. 4–1:** Definition of magnetic switching points for the HAL526

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+140\text{ °C}$ ,  $V_{DD} = 3.8\text{ V}$  to  $24\text{ V}$ , Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points. Positive flux density values refer to the magnetic south pole at the branded side of the package.

Parameter	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Magnetic Offset			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
$T_J$													
-40 °C	11.8	15.8	19.2	-19.2	-15.8	-11.8	27.4	31.6	35.8		0		mT
25 °C	11	14	17	-17	-14	-11	24	28	32	-2	0	2	mT
100 °C	8	11	15.5	-15.5	-11	-8	18.5	22	28.7		0		mT
140 °C	6.5	10	14	-14	-10	-6.5	16	20	26		0		mT

The hysteresis is the difference between the switching points  $B_{HYS} = B_{ON} - B_{OFF}$   
 The magnetic offset is the mean value of the switching points  $B_{OFFSET} = (B_{ON} + B_{OFF}) / 2$



**Note:** In the diagram “Magnetic switching points versus ambient temperature”, the curves for  $B_{ONmin}$ ,  $B_{ONmax}$ ,  $B_{OFFmin}$ , and  $B_{OFFmax}$  refer to junction temperature, whereas typical curves refer to ambient temperature.

**4.2. HAL535**

The HAL535 is a latching sensor (see Fig. 4–5).

The output turns low with the magnetic south pole on the branded side of the package and turns high with the magnetic north pole on the branded side. The output does not change if the magnetic field is removed. For changing the output state, the opposite magnetic field polarity must be applied.

For correct functioning in the application, the sensor requires both magnetic polarities (north and south) on the branded side of the package.

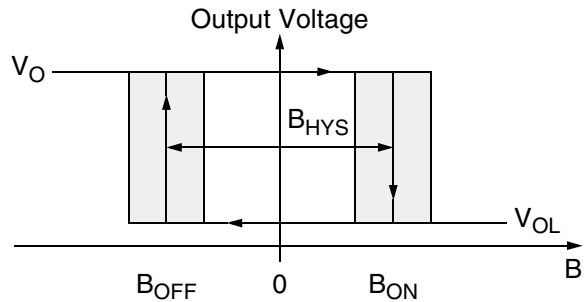
**Magnetic Features:**

- switching type: latching
- low sensitivity
- typical  $B_{ON}$ : 13.8 mT at room temperature
- typical  $B_{OFF}$ : -13.8 mT at room temperature
- operates with static magnetic fields and dynamic magnetic fields up to 10 kHz
- typical temperature coefficient of magnetic switching points is -1000 ppm/K

**Applications**

The HAL535 is the optimal sensor for applications with alternating magnetic signals such as:

- multipole magnet applications,
- rotating speed measurement,
- commutation of brushless DC motors, and
- window lifter.



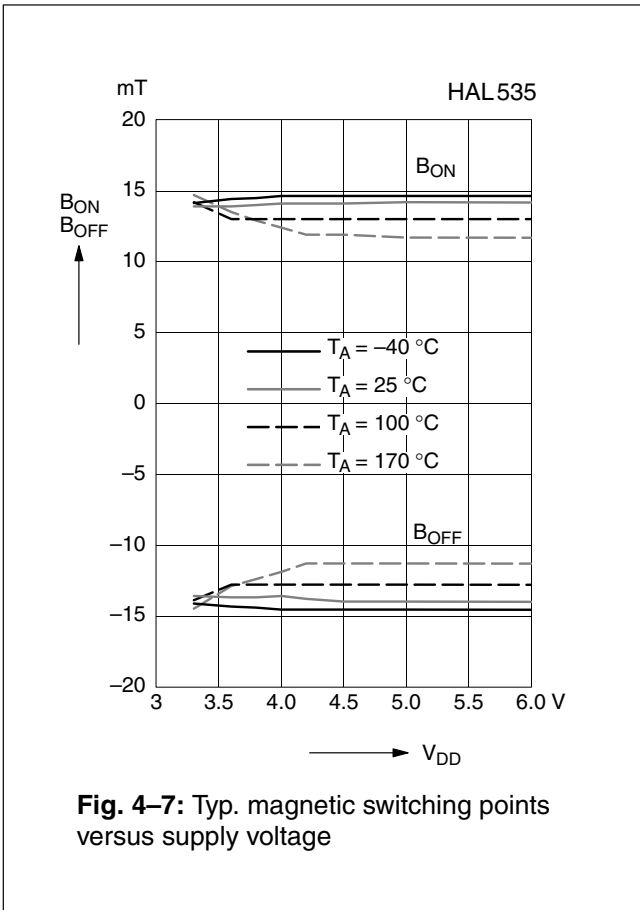
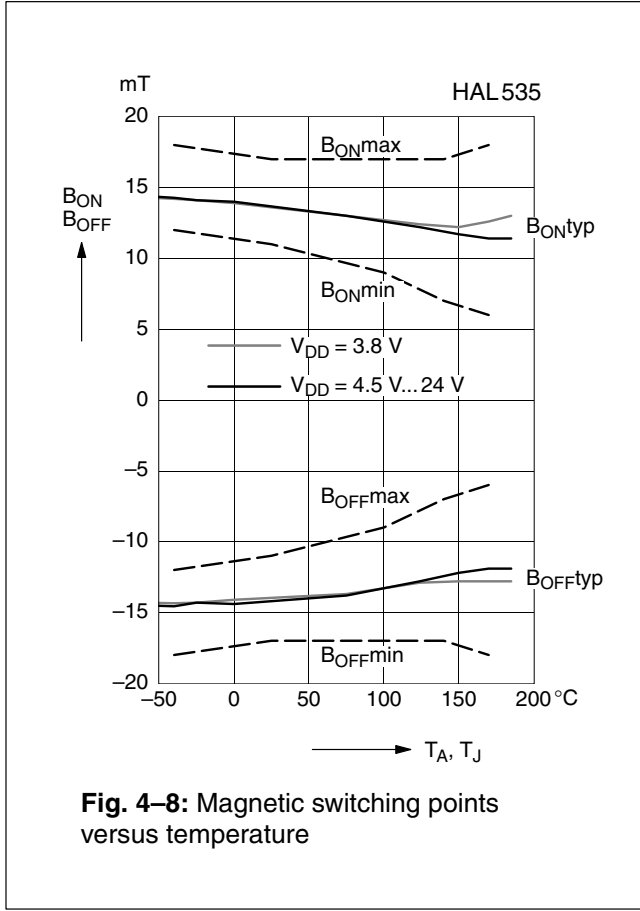
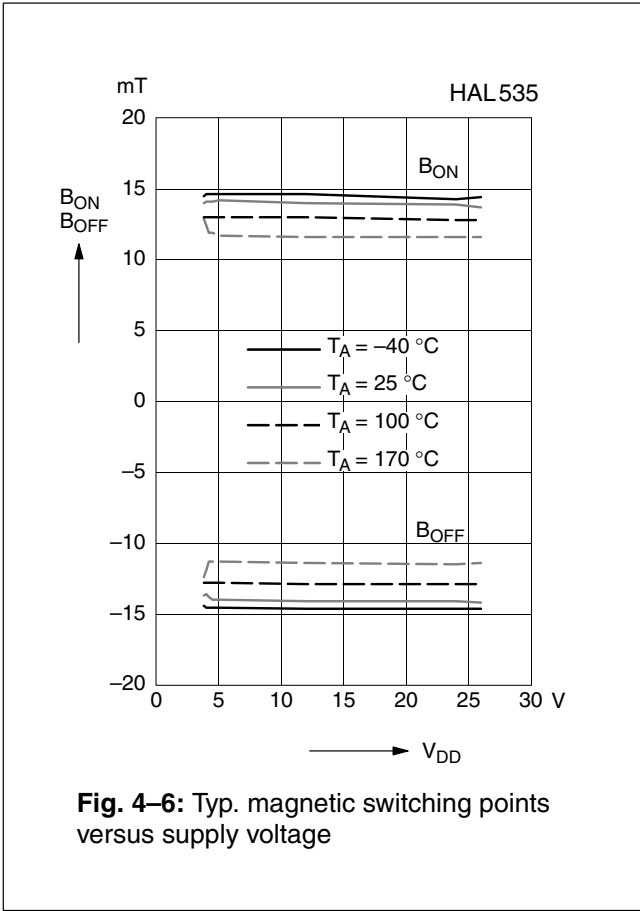
**Fig. 4–5:** Definition of magnetic switching points for the HAL535

**Magnetic Characteristics** at  $T_J = -40\text{ °C}$  to  $+140\text{ °C}$ ,  $V_{DD} = 3.8\text{ V}$  to  $24\text{ V}$ , Typical Characteristics for  $V_{DD} = 12\text{ V}$

Magnetic flux density values of switching points. Positive flux density values refer to the magnetic south pole at the branded side of the package.

Parameter	On point $B_{ON}$			Off point $B_{OFF}$			Hysteresis $B_{HYS}$			Magnetic Offset			Unit
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
$T_J$													
-40 °C	12	15	18	-18	-15	-12	25	30	35		0		mT
25 °C	11	13.8	17	-17	-13.8	-11	23	27.6	32		0		mT
100 °C	9	13	17	-17	-13	-9	20	26	31.5		0		mT
140 °C	7	12.5	17	-17	-12.5	-7	18	25	31		0		mT

The hysteresis is the difference between the switching points  $B_{HYS} = B_{ON} - B_{OFF}$   
 The magnetic offset is the mean value of the switching points  $B_{OFFSET} = (B_{ON} + B_{OFF}) / 2$



**Note:** In the diagram “Magnetic switching points versus ambient temperature”, the curves for  $B_{ONmin}$ ,  $B_{ONmax}$ ,  $B_{OFFmin}$ , and  $B_{OFFmax}$  refer to junction temperature, whereas typical curves refer to ambient temperature.

## 5. Application Notes

### WARNING:

DO NOT USE THESE SENSORS IN LIFE-SUPPORTING SYSTEMS, AVIATION, AND AEROSPACE APPLICATIONS.

### 5.1. Ambient Temperature

Due to the internal power dissipation, the temperature on the silicon chip (junction temperature  $T_J$ ) is higher than the temperature outside the package (ambient temperature  $T_A$ ).

$$T_J = T_A + \Delta T$$

At static conditions and continuous operation, the following equation applies:

$$\Delta T = I_{DD} * V_{DD} * R_{th}$$

For typical values, use the typical parameters. For worst case calculation, use the max. parameters for  $I_{DD}$  and  $R_{th}$ , and the max. value for  $V_{DD}$  from the application.

For all sensors, the junction temperature range  $T_J$  is specified. The maximum ambient temperature  $T_{Amax}$  can be calculated as:

$$T_{Amax} = T_{Jmax} - \Delta T$$

### 5.2. Extended Operating Conditions

All sensors fulfill the electrical and magnetic characteristics when operated within the Recommended Operating Conditions (see page 12).

#### Supply Voltage Below 3.8 V

Typically, the sensors operate with supply voltages above 3 V, however, below 3.8 V some characteristics may be outside the specification.

**Note:** The functionality of the sensor below 3.8 V is not tested. For special test conditions, please contact Micronas.

### 5.3. Start-up Behavior

Due to the active offset compensation, the sensors have an initialization time (enable time  $t_{en(O)}$ ) after applying the supply voltage. The parameter  $t_{en(O)}$  is specified in the Characteristics (see page 13).

During the initialization time, the output state is not defined and the output can toggle. After  $t_{en(O)}$ , the output will be low if the applied magnetic field  $B$  is above  $B_{ON}$ . The output will be high if  $B$  is below  $B_{OFF}$ .

For magnetic fields between  $B_{OFF}$  and  $B_{ON}$ , the output state of the HAL sensor after applying  $V_{DD}$  will be either low or high. In order to achieve a well-defined output state, the applied magnetic field must be above  $B_{ONmax}$ , respectively, below  $B_{OFFmin}$ .

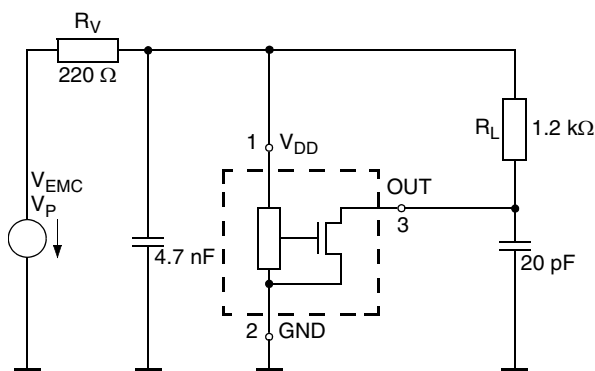
### 5.4. EMC and ESD

For applications with disturbances on the supply line or radiated disturbances, a series resistor and a capacitor are recommended (see Fig. 5–1). The series resistor and the capacitor should be placed as closely as possible to the HAL sensor.

Applications with this arrangement passed the EMC tests according to the product standards DIN 40839.

**Note:** The international standard ISO 7637 is similar to the used product standard DIN 40839.

Please contact Micronas for the detailed investigation reports with the EMC and ESD results.



**Fig. 5–1:** Test circuit for EMC investigations



**6. Data Sheet History**

1. Final data sheet: "HAL525 Hall Effect Sensor IC", April 23, 1997, 6251-465-1DS. First release of the final data sheet.
2. Final data sheet: "HAL525 Hall Effect Sensor IC", March 10, 1999, 6251-465-2DS. Second release of the final data sheet. Major changes:
  - additional package SOT-89B
  - outline dimensions for SOT-89A and TO-92UA changed
  - electrical characteristics changed
  - section 4.2.: Extended Operating Conditions added
  - section 4.3.: Start-up Behavior added
3. Final data sheet: "HAL525, HAL535 Hall Effect Sensor Family", Aug. 30, 2000, 6251-465-3DS. Third release of the final data sheet. Major changes:
  - new sensor HAL 535 added
  - outline dimensions for SOT-89B: reduced tolerances
  - SMD package SOT-89A removed
  - temperature range "C" removed
4. Data Sheet: "HAL525, HAL535 Hall Effect Sensor Family", Aug. 8, 2002, 6251-465-4DS. Fourth release of the data sheet. Major changes:
  - outline dimensions for TO-92UA changed
  - temperature range "A" removed
5. Data Sheet: "HAL525, HAL526, HAL535 Hall Effect Sensor Family", Oct. 22, 2002, 6251-465-5DS. Fifth release of the data sheet. Major changes:
  - new sensor HAL 526 added
6. Data Sheet: "HAL526, HAL535 Hall Effect Sensor Family", March 31, 2004, 6251-465-6DS. Sixth release of the data sheet. Major changes:
  - specification for HAL 525 removed
  - new package diagrams for SOT89B-1 and TO92UA-1
  - package diagram for TO92UA-2 added
  - ammpack diagrams for TO92UA-1/-2 added

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